



TPTS3A5018PWR

Low On Resistance, Quad SPDT Analog Switch

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Features

- Supply voltage: 1.5 ~ 5.5V
- ultra-low On Resistance: 1.5 Ω
- -3dB Bandwidth :700MHz
- Rail-to-Rail Signal Range
- Break-Before-Make Switching
- Low quiescent current over an Expanded Control Input Range
- Standard Products are Pb-free and halogen-free
- Packaging: TSSOP-16

General Description

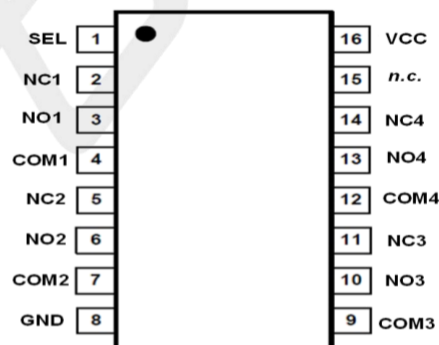
The is a high performance, quad, Single Pole Double Throw (SPDT) analog switch that features ultra-low Ron of 1.5 Ω (typical) at 4.5V VCC. The operates over a wide VCC range of 2.3V to 4.5V and is designed for break-before-make operation. The select input is TTL-level compatible.

The is also featured with smart circuitry to minimize VCC leakage current even when the control voltage is lower than VCC supply voltage. This feature suits mobile handset applications by allowing direct interface with baseband processor general-purpose IO with minimal battery consumption. In other word, there is no need of additional device to shift control level to be the same as that of VCC in real application.

Applications

- Other electronics equipment
- Audio and Video Signal Routing
- LCD Monitor, TV and Set-Top Box
- Cell phones, PDA, Digital Camera and Notebook

PIN CONFIGURATIONS (Top view)

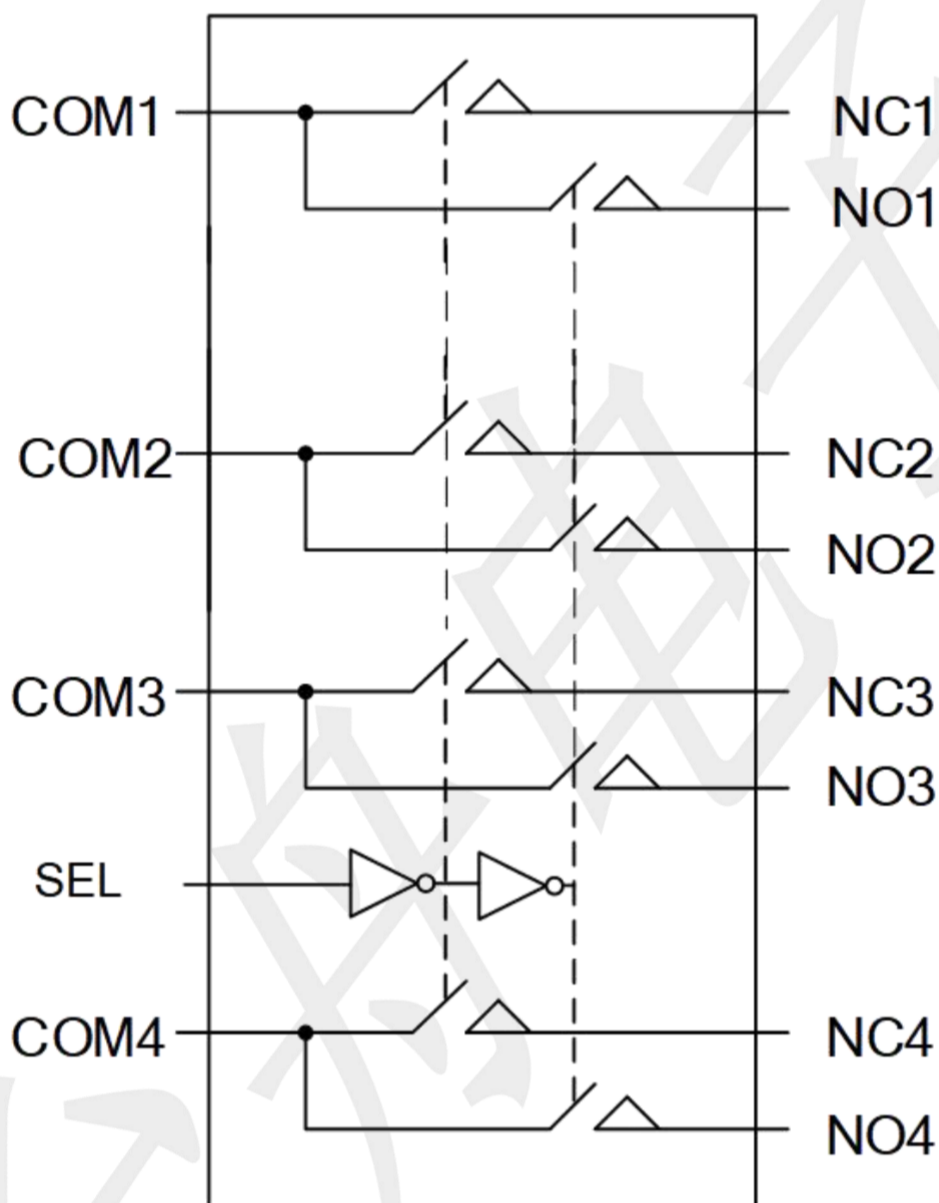


PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION	PIN NO.	PIN NAME	DESCRIPTION
1	SEL	Logic Input Control	9	COM3	Common Data Port
2	NC1	Data Port (Normally closed)	10	NO3	Data Port (Normally open)
3	NO1	Data Port (Normally open)	11	NC3	Data Port (Normally closed)
4	COM1	Common Data Port	12	COM4	Common Data Port
5	NC2	Data Port (Normally closed)	13	NO4	Data Port (Normally open)
6	NO2	Data Port (Normally open)	14	NC4	Data Port (Normally closed)
7	COM2	Common Data Port	15	N.C.	No Internal Connection
8	GND	Ground	16	VCC	Positive Power Supply



BLOCK DIAGRAM



Function Descriptions

SEL	Function
0	NC1 Connected to COM1, NC2 Connected to COM2 NC3 Connected to COM3, NC4 Connected to COM4
1	NO1 Connected to COM1, NO2 Connected to COM2 NO3 Connected to COM3, NO4 Connected to COM4



Absolute Maximum Ratings

(Unless otherwise specified) ⁽¹⁾

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	-0.3 ~ 6.5	V
Control Input Voltage	V_{IN}	-0.3 ~ 6.5	V
DC Input Voltage ⁽²⁾	V_{INPUT}	-0.3 ~ 6.5	V
Continuous Current NO_NC_COM_		±100	mA
Peak Current NO_NC_COM_ (pulsed at 1ms 50% duty cycle)		±200	mA
Peak Current NO_NC_COM_ (pulsed at 1ms 10% duty cycle)		±200	mA
Storage Temperature Range	T_{STG}	-65 ~ 150	°C
Junction Temperature under Bias	T_J	150	°C
Lead Temperature (Soldering, 10 seconds)	T_L	260	°C
Power Dissipation	P_D	250	mW

Recommend operating ratings

(Unless otherwise specified) ⁽³⁾

Parameter	Symbol	Value	Unit
Supply Voltage Operating	V_{CC}	1.5 ~ 5.5	V
Control Input Voltage	V_{IN}	0.0 ~ V_{CC}	V
Input Signal Voltage	V_{IS}	0.0 ~ V_{CC}	V
Operating Temperature	T_A	-40 ~ 85	°C
Input Raise and Fall Time(Control Input $V_{CC}=2.3\sim 3.6V$)	t_r, t_f	0 ~ 10	ns/V
Thermal Resistance	$R_{\theta JA}$	350	°C/W

Note:

1. "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
2. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.
3. Control input must be held high or Low, it must not float.



DC Electronics Characteristics

(Ta=25°C, VCC=4.5V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input logic high level	V _{IH}	VCC: 3.0 ~ 4.5	1.6	--	--	V
		VCC: 2.3 ~ 3.0	1.4	--	--	V
Input logic low level	V _{IL}	VCC: 3.0 ~ 4.5	--	--	0.6	V
		VCC: 2.3 ~ 3.0	--	--	0.4	V
Supply quiescent current	I _{CC}	I _{OUT} =0, V _{IN} =0 or V _{IN} =VCC	--	--	1.0	uA
Increase in I _{CC} per input	I _{CCCT}	I _{OUT} =0, VCC=4.5 V _{IN} >1.8 or V _{IN} <0.5	--	--	2.0	uA
Input leakage current	I _{IN}	V _{SEL} =VCC	--	--	±1.0	uA
Off state switch leakage current	I _{OFF}		--	--	±1.0	uA
On state switch leakage current	I _{ON}		--	--	±1.0	uA
On-Resistance	R _{ON}	VCC=4.5V, V _{IS} =0~4.5V, I _{ON} =100mA,	--	1.5	--	Ω
		VCC=3.0V, V _{IS} =0~3.0V, I _{OUT} =100mA,	--	1.8	--	Ω
On-Resistance Matching Between Channels	Δ R _{ON}	VCC=4.5V, V _{IS} =0.8V, I _{OUT} =100mA,	--	0.1	--	Ω
		VCC=3.0V, V _{IS} =0.8V, I _{OUT} =100mA,	--	0.14	--	Ω
On-Resistance Flatness	R _{FLAT(ON)}	VCC=4.5V, V _{IS} =0~4.5V, I _{OUT} =100mA,	--	--	0.5	Ω
		VCC=3.0V, V _{IS} =0~3.0V, I _{OUT} =100mA,	--	--	0.8	Ω



AC Electronics Characteristics

(Ta=25°C, VCC=4.5V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Turn-On Time	T _{ON}	VCC=4.5V, V _{IS} =1.5V, C _L =35pF, R _L =50Ω	--	200	--	ns
Turn-Off Time	T _{OFF}	VCC=4.5V, V _{IS} =1.5V, C _L =35pF, R _L =50Ω	--	200	--	ns
Break-Before-Make time	T _{BBM}	Generate by design	--	100	--	ns
-3dB Bandwidth	BW	R _L =50Ω, C _L =0pF	--	700	--	MHz
Off isolation (Per Channel)	OIRR	F=100KHz, R _L =50Ω	--	-50	--	dB
Crosstalk (Channel to Channel)	Xtalk	F=100KHz, R _L =50Ω	--	-50	--	dB
Total Harmonic Distortion	THD	F=20Hz to 20KHz R _L =32Ω, V _{IS} =0.5Vp-p	--	-80	--	dB

Capacitance

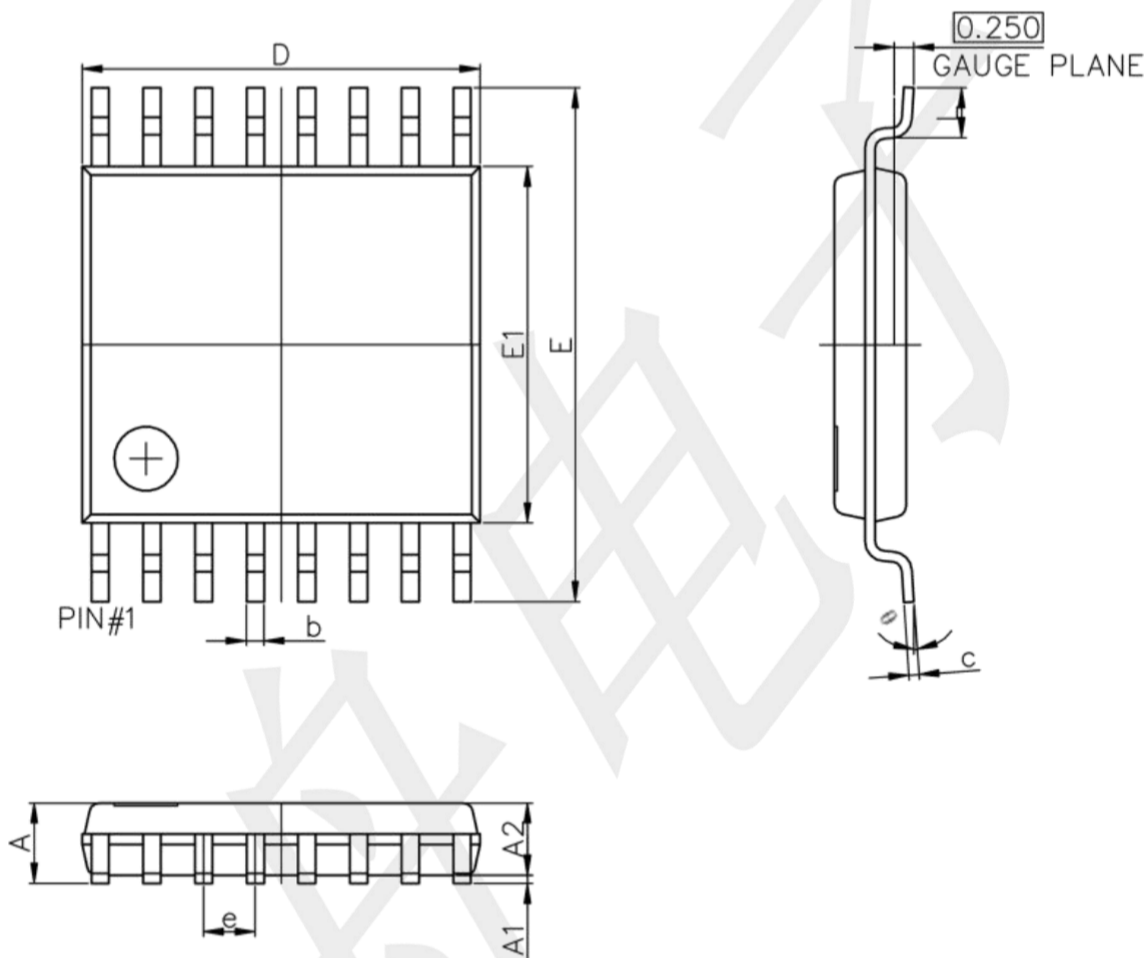
(Ta=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Off capacitance	C _{OFF}	F=1MHz, VCC=3.3V	--	5	--	pF
On capacitance	C _{ON}	F=1MHz, VCC=3.3V	--	8	--	pF



Package information

TSSOP-16



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	—	1.200	—	0.047
A1	0.020	0.100	0.001	0.004
A2	0.800	1.000	0.031	0.039
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.900	5.100	0.193	0.201
e	0.650(BSC)		0.026(BSC)	
E	6.250	6.550	0.252(BSC)	
E1	4.300	4.500	0.169	0.177
L	0.500	0.700	0.020	0.028
θ	1°	7°	1°	7°